

高绝缘等级模块  
high insulated module



$V_{CES} = 4500V$   
 $I_{C\ nom} = 1200A / I_{CRM} = 2400A$

### 潜在应用

- 中压变流器
- 多电平逆变器
- 大功率变流器
- 牵引变流器
- 电机传动
- 风力发电机

### 电气特性

- 高冲击电流能力
- 高动态坚固性
- 高直流电压稳定性

### 机械特性

- 加强绝缘封装，10.4kV 交流 10 第二
- 封装的 CTI > 600
- 碳化硅铝 (AlSiC) 基板提供更高的温度循环能力
- 高爬电距离和电气间隙

### Potential Applications

- Medium voltage converters
- Multi level inverter
- High power converters
- Traction drives
- Motor drives
- Wind turbines

### Electrical Features

- High surge current capability
- High dynamic robustness
- High DC stability

### Mechanical Features

- Package with enhanced insulation of 10.4kV AC 10s
- Package with CTI > 600
- AlSiC base plate for increased thermal cycling capability
- High creepage and clearance distances

## Module Label Code

Barcode Code 128



DMX - Code



### Content of the Code

| Content of the Code        | Digit   |
|----------------------------|---------|
| Module Serial Number       | 1 - 5   |
| Module Material Number     | 6 - 11  |
| Production Order Number    | 12 - 19 |
| Datecode (Production Year) | 20 - 21 |
| Datecode (Production Week) | 22 - 23 |

**二极管, 逆变器 / Diode, Inverter**  
**最大额定值 / Maximum Rated Values**

|   |   |                      |                      |                       |
|---|---|----------------------|----------------------|-----------------------|
| 反向重复峰值电压<br>Repetitive peak reverse voltage | $T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = -40^{\circ}\text{C}$ | $V_{RRM}$            | 4500<br>4500<br>4500 | V                     |
| 连续正向直流电流<br>Continuous DC forward current   |   | $I_F$                | 1200                 | A                     |
| 正向重复峰值电流<br>Repetitive peak forward current | $t_p = 1 \text{ ms}$  | $I_{FRM}$            | 2400                 | A                     |
| $I^2t$ -值<br>$I^2t$ - value                 | $V_R = 0 \text{ V}, t_p = 10 \text{ ms}, T_{vj} = 125^{\circ}\text{C}$                            | $I^2t$               | 570                  | $\text{kA}^2\text{s}$ |
| 最大损耗功率<br>Maximum power dissipation         | $T_{vj} = 125^{\circ}\text{C}$  | $P_{RQM}$            | 2400                 | kW                    |
| 最小开通时间<br>Minimum turn-on time              |   | $t_{on \text{ min}}$ | 10,0                 | $\mu\text{s}$         |

**特征值 / Characteristic Values**

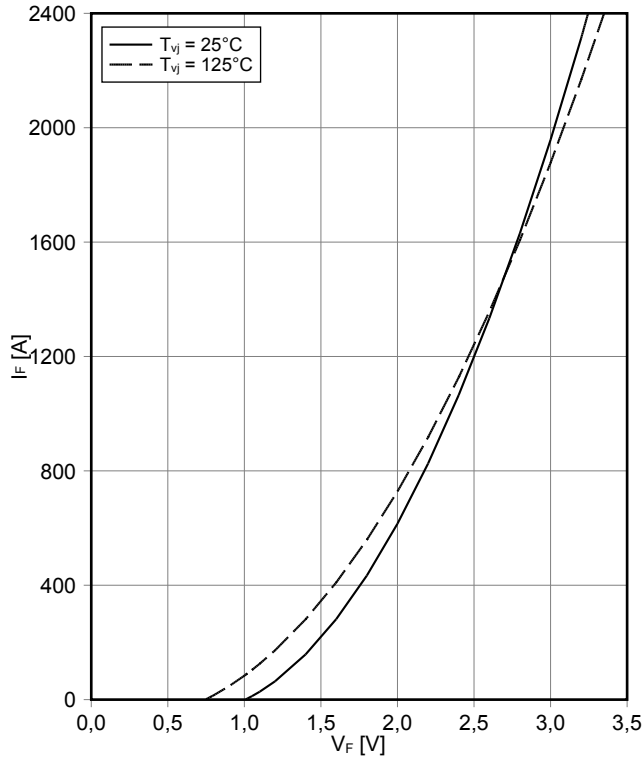
|  |   |   | min.                | typ.         | max.         |                                |
|--|---|---|---------------------|--------------|--------------|--------------------------------|
| 正向电压<br>Forward voltage                            | $I_F = 1200 \text{ A}, V_{GE} = 0 \text{ V}$<br>$I_F = 1200 \text{ A}, V_{GE} = 0 \text{ V}$  | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$ | $V_F$               | 2,50<br>2,50 | 3,10<br>3,00 | V<br>V                         |
| 反向恢复峰值电流<br>Peak reverse recovery current          | $I_F = 1200 \text{ A}, -di_F/dt = 5000 \text{ A}/\mu\text{s} (T_{vj}=125^{\circ}\text{C})$<br>$V_R = 2800 \text{ V}$<br>$V_{GE} = -15 \text{ V}$    | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$ | $I_{RM}$            | 1500<br>1700 |              | A<br>A                         |
| 恢复电荷<br>Recovered charge                           | $I_F = 1200 \text{ A}, -di_F/dt = 5000 \text{ A}/\mu\text{s} (T_{vj}=125^{\circ}\text{C})$<br>$V_R = 2800 \text{ V}$<br>$V_{GE} = -15 \text{ V}$    | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$ | $Q_r$               | 1150<br>2100 |              | $\mu\text{C}$<br>$\mu\text{C}$ |
| 反向恢复损耗 (每脉冲)<br>Reverse recovery energy            | $I_F = 1200 \text{ A}, -di_F/dt = 5000 \text{ A}/\mu\text{s} (T_{vj}=125^{\circ}\text{C})$<br>$V_R = 2800 \text{ V}$<br>$V_{GE} = -15 \text{ V}$    | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$ | $E_{rec}$           | 1750<br>3550 |              | mJ<br>mJ                       |
| 结 - 外壳热阻<br>Thermal resistance, junction to case   | 每个二极管 / per diode   |   | $R_{thJC}$          |              | 17,0         | K/kW                           |
| 外壳 - 散热器热阻<br>Thermal resistance, case to heatsink | 每个二极管 / per diode<br>$\lambda_{\text{Paste}} = 1 \text{ W}/(\text{m}\cdot\text{K}) / \lambda_{\text{grease}} = 1 \text{ W}/(\text{m}\cdot\text{K})$ |   | $R_{thCH}$          |              | 16,0         | K/kW                           |
| 在开关状态下温度<br>Temperature under switching conditions |   |   | $T_{vj \text{ op}}$ | -50          | 125          | $^{\circ}\text{C}$             |

## 模块 / Module

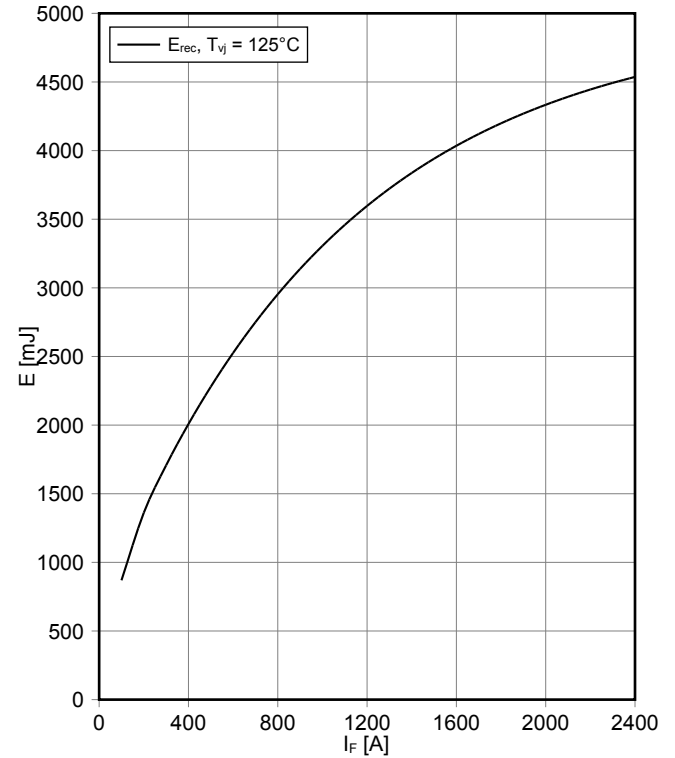
|   |  |                     |              |      |         |
|---|--|---------------------|--------------|------|---------|
| 绝缘测试电压<br>Isolation test voltage                          | RMS, f = 50 Hz, t = 10 s   | V <sub>ISOL</sub>   | 10,4         |      | kV      |
| 局部放电停止电压<br>Partial discharge extinction voltage          | RMS, f = 50 Hz, Q <sub>PD</sub> ≤ 10 pC  | V <sub>ISOL</sub>   | 3,5          |      | kV      |
| DC 稳定性<br>DC stability                                    | T <sub>vj</sub> = 25°C, 100 fit  | V <sub>CE D</sub>   | 3000         |      | V       |
| 模块基板材料<br>Material of module baseplate                    |  |                     | AISiC        |      |         |
| 内部绝缘<br>Internal isolation                                | 基本绝缘 (class 1, IEC 61140)<br>basic insulation (class 1, IEC 61140)             |                     | AIN          |      |         |
| 爬电距离<br>Creepage distance                                 | 端子至散热器 / terminal to heatsink<br>端子至端子 / terminal to terminal                  |                     | 56,0<br>56,0 |      | mm      |
| 电气间隙<br>Clearance   | 端子至散热器 / terminal to heatsink<br>端子至端子 / terminal to terminal                  |                     | 26,0<br>26,0 |      | mm      |
| 相对电痕指数<br>Comperative tracking index                      |  | CTI                 | > 600        |      |         |
|   |  |                     | min.         | typ. | max.    |
| 杂散电感, 模块<br>Stray inductance module                       |  | L <sub>sCE</sub>    |              | 25   | nH      |
| 模块引线电阻, 端子-芯片<br>Module lead resistance, terminals - chip | T <sub>c</sub> = 25°C, 每个开关 / per switch                                       | R <sub>AA+CC'</sub> |              | 0,37 | mΩ      |
| 储存温度<br>Storage temperature                               |  | T <sub>stg</sub>    | -55          |      | 125 °C  |
| 模块安装的安装扭矩<br>Mounting torque for modul mounting           | 螺丝 M6 根据相应的应用手册进行安装<br>Screw M6 - Mounting according to valid application note | M                   | 4,25         |      | 5,75 Nm |
| 端子联接扭矩<br>Terminal connection torque                      | 螺丝 M8 根据相应的应用手册进行安装<br>Screw M8 - Mounting according to valid application note | M                   | 8,0          | -    | 10 Nm   |
| 重量<br>Weight  |  | G                   |              | 1000 | g       |

Dynamische Daten gelten in Verbindung mit FZ1200R45KL3\_B5 Modul  
Dynamic Data valid in conjunction with FZ1200R45KL3\_B5 module

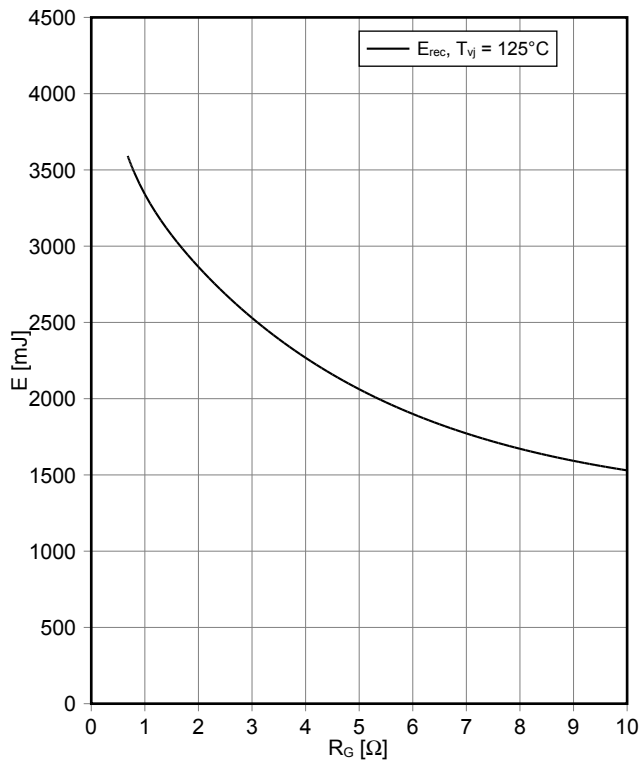
正向偏压特性 二极管,逆变器 (典型)  
**forward characteristic of Diode, Inverter (typical)**  
 $I_F = f(V_F)$



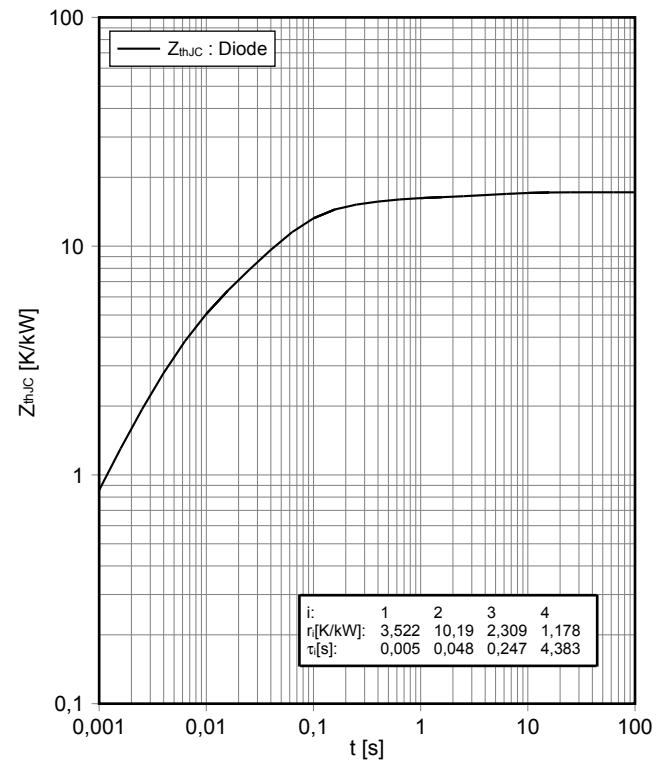
开关损耗 二极管,逆变器 (典型)  
**switching losses Diode, Inverter (typical)**  
 $E_{rec} = f(I_F)$   
 $-di_F/dt = 5000\text{A}/\mu\text{s}, V_{CE} = 2800\text{V}$



开关损耗 二极管,逆变器 (典型)  
**switching losses Diode, Inverter (typical)**  
 $E_{rec} = f(R_G)$   
 $I_F = 1200\text{A}, V_{CE} = 2800\text{V}$

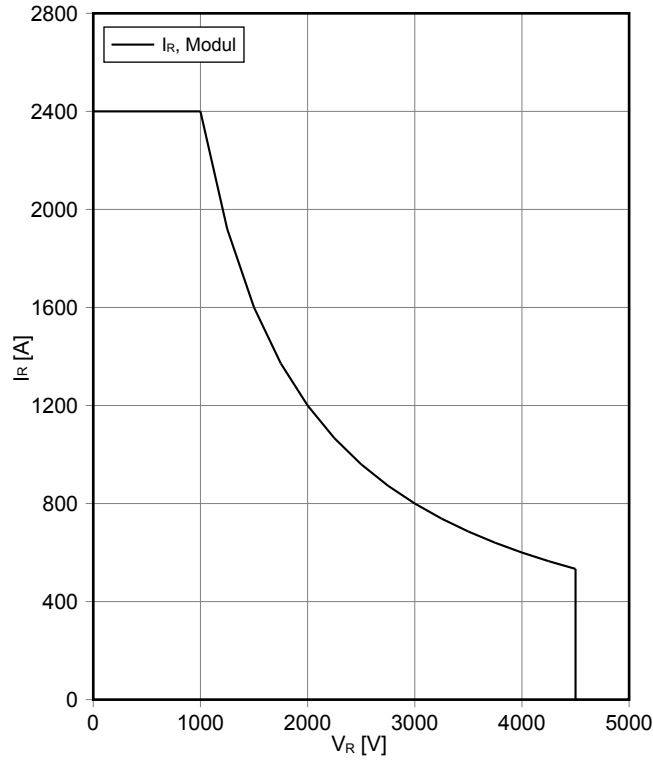


瞬态热阻抗 二极管,逆变器  
**transient thermal impedance Diode, Inverter**  
 $Z_{thJC} = f(t)$

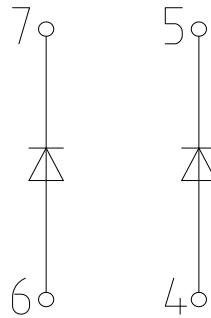


安全工作区 二极管, 逆变器 (SOA)  
safe operation area Diode, Inverter (SOA)

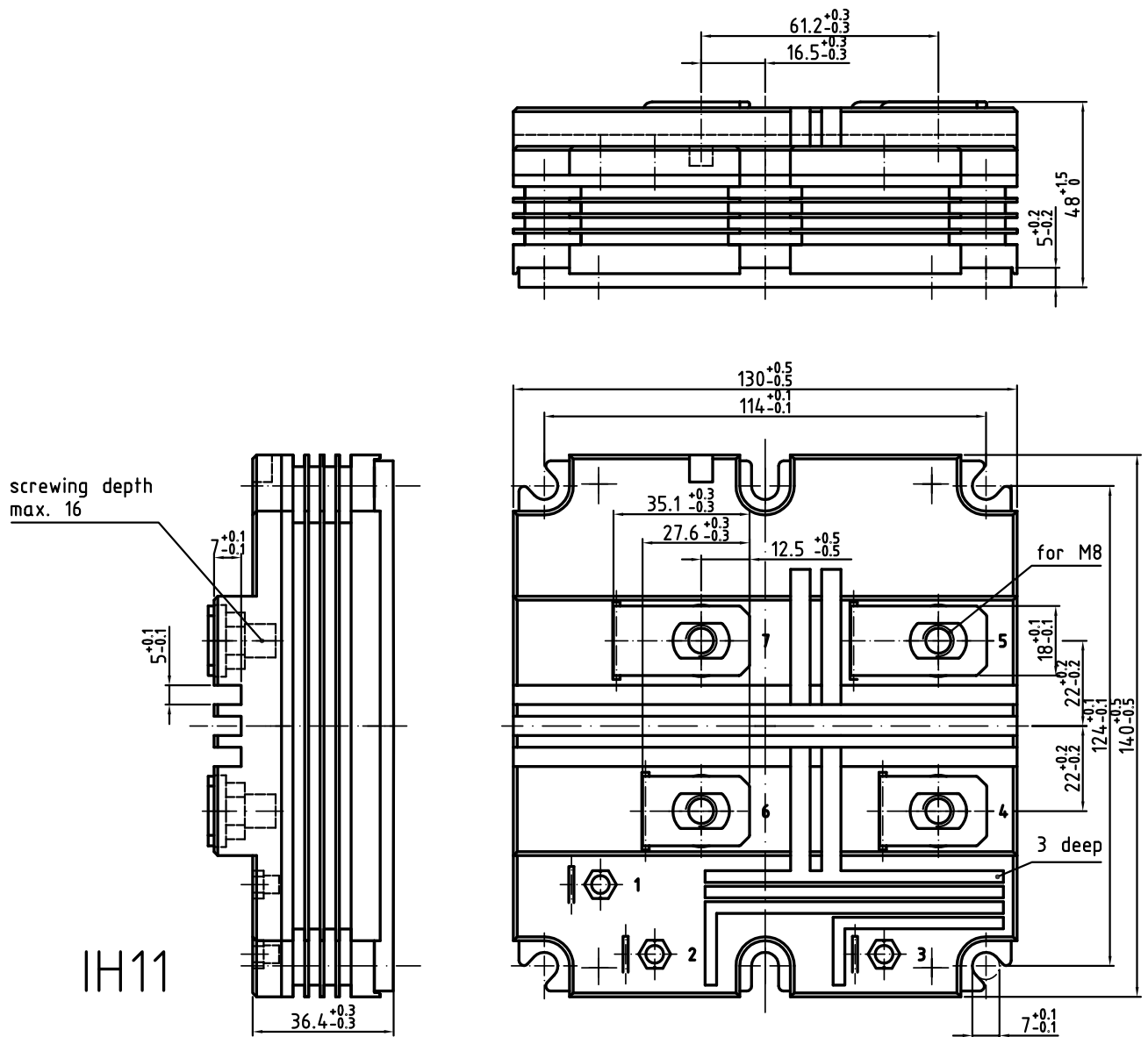
$I_R = f(V_R)$   
 $T_{vj} = 125^\circ\text{C}$



## 接线图 / Circuit diagram



## 封装尺寸 / Package outlines



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